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This listing of claims will replace all prior versions of claims in the application.

Claims 1-44. (cancelled)

Claim 45. (new) A chemically-acting positive-acting photoresist composition comprising:

- a) a resin that comprises photoacid-labile groups; and
- b) one or more photoacid generator compounds that upon exposure to activating radiation generate an acid of the formula R(CR<sup>1</sup>R<sup>2</sup>)CF<sub>2</sub>SO<sub>3</sub>H,

where R is an optionally substituted alkyl having 4 to about 20 carbon atoms, optionally substituted alicyclic group, optionally substituted carbocyclic aryl group, optionally substituted heteroalicyclic group, or optionally substituted heteroaromatic group, and R is not perhaloalkyl; and

R<sup>1</sup> and R<sup>2</sup> are each independently hydrogen or a non-hydrogen substituent.

- Claim 46. (new) The photoresist composition of claim 45 wherein R is optionally substituted alkyl.
- Claim 47. (new) The photoresist composition of claim 45 wherein R is an optionally substituted alicyclic group.
- Claim 48. (new) The photoresist composition of claim 45 wherein R is an optionally substituted carbocyclic aryl group.
- Claim 49. (new) The photoresist composition of claim 45 wherein R is an optionally substituted heteroalicyclic group, or optionally substituted heteroaromatic group,

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- Claim 50. (new) The photoresist composition of claim 45 wherein the one or more photoacid generator compounds are iodonium compounds.
- Claim 51. (new) The photoresist composition of claim 45 wherein the one or more photoacid generator compounds are sulfonium compounds.
- Claim 52. (new) The photoresist composition of claim 45 wherein the one or more photoacid generator compounds are non-ionic compounds.
- Claim 53. (new) The photoresist composition of claim 52 wherein the one or more photoacid generator compounds are sulfonate compounds.
- Claim 54. (new) The photoresist composition of claim 45 wherein the one or more photoacid generator compounds are N-oxyimidosulfonate compounds or N-oxyimidosulfonate compounds.
- Claim 55. (new) The photoresist composition of claim 45 wherein the one or more photoacid generator compounds are diazosulfone compounds.
- Claim 56. (new) The photoresist composition of claim 45 wherein the resin comprises phenolic groups.
- Claim 57. (new) The photoresist composition of claim 45 wherein the resin is at least substantially free of aromatic groups.
- Claim 58. (new) The photoresist composition of claim 45 wherein the resin is completely free of aromatic groups.

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Claim 59. (new) An article of manufacture comprising a coating layer of a photoresist composition of claim 45.

Claim 60. (new) The article of manufacture of claim 59 wherein the article is a microelectronic wafer substrate.